



# 74HC3G14-Q100; 74HCT3G14-Q100

Triple inverting Schmitt trigger

Rev. 4 — 18 December 2023

Product data sheet

## 1. General description

The 74HC3G14-Q100; 74HCT3G14-Q100 is a triple inverter with Schmitt-trigger inputs. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of  $V_{CC}$ . Schmitt trigger inputs transform slowly changing input signals into sharply defined jitter-free output signals.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

## 2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
  - Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Wide supply voltage range from 2.0 V to 6.0 V
- Input levels:
  - For 74HC3G14-Q100: CMOS level
  - For 74HCT3G14-Q100: TTL level
- CMOS low power dissipation
- High noise immunity
- Unlimited input rise and fall times
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- Complies with JEDEC standards:
  - JESD8C (2.7 V to 3.6 V)
  - JESD7A (2.0 V to 6.0 V)
- ESD protection:
  - HBM: ANSI/ESDA/JEDEC JS-001 class 2 exceeds 2000 V
  - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V

## 3. Applications

- Wave and pulse shaper for highly noisy environments
- Astable multivibrators
- Monostable multivibrators

## 4. Ordering information

Table 1. Ordering information

| Type number                                                         | Package           |        |                                                                                         |                          |
|---------------------------------------------------------------------|-------------------|--------|-----------------------------------------------------------------------------------------|--------------------------|
|                                                                     | Temperature range | Name   | Description                                                                             | Version                  |
| <a href="#">74HC3G14DP-Q100</a><br><a href="#">74HCT3G14DP-Q100</a> | -40 °C to +125 °C | TSSOP8 | plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm | <a href="#">SOT505-2</a> |
| <a href="#">74HC3G14DC-Q100</a><br><a href="#">74HCT3G14DC-Q100</a> | -40 °C to +125 °C | VSSOP8 | plastic very thin shrink small outline package; 8 leads; body width 2.3 mm              | <a href="#">SOT765-1</a> |

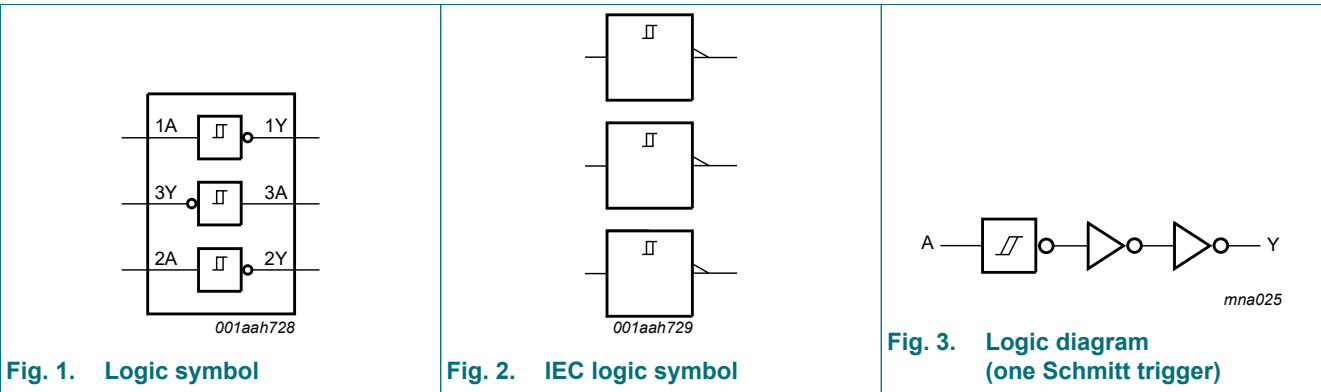
5. Marking

Table 2. Marking

| Type number      | Marking code [1] |
|------------------|------------------|
| 74HC3G14DP-Q100  | H14              |
| 74HCT3G14DP-Q100 | T14              |
| 74HC3G14DC-Q100  | H14              |
| 74HCT3G14DC-Q100 | T14              |

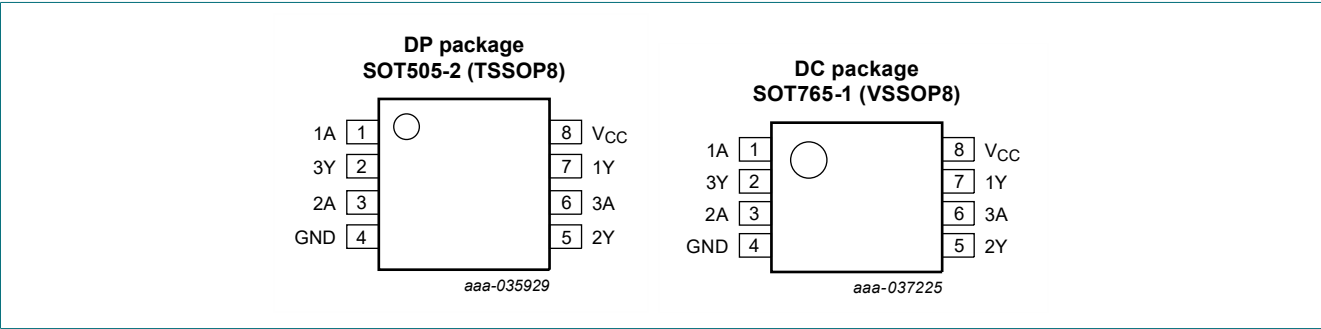
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

6. Functional diagram



7. Pinning information

7.1. Pinning



7.2. Pin description

Table 3. Pin description

| Symbol          | Pin     | Description    |
|-----------------|---------|----------------|
| 1A, 2A, 3A      | 1, 3, 6 | data input     |
| GND             | 4       | ground (0 V)   |
| 1Y, 2Y, 3Y      | 7, 5, 2 | data output    |
| V <sub>CC</sub> | 8       | supply voltage |

8. Functional description

Table 4. Function table

H = HIGH voltage level; L = LOW voltage level.

| Input | Output |
|-------|--------|
| nA    | nY     |
| L     | H      |
| H     | L      |

9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol           | Parameter               | Conditions                                                              | Min  | Max  | Unit |
|------------------|-------------------------|-------------------------------------------------------------------------|------|------|------|
| V <sub>CC</sub>  | supply voltage          |                                                                         | -0.5 | +7.0 | V    |
| I <sub>IK</sub>  | input clamping current  | V <sub>I</sub> < -0.5 V or V <sub>I</sub> > V <sub>CC</sub> + 0.5 V [1] | -    | ±20  | mA   |
| I <sub>OK</sub>  | output clamping current | V <sub>O</sub> < -0.5 V or V <sub>O</sub> > V <sub>CC</sub> + 0.5 V [1] | -    | ±20  | mA   |
| I <sub>O</sub>   | output current          | V <sub>O</sub> = -0.5 V to V <sub>CC</sub> + 0.5 V [1]                  | -    | ±25  | mA   |
| I <sub>CC</sub>  | supply current          | [1]                                                                     | -    | +50  | mA   |
| I <sub>GND</sub> | ground current          | [1]                                                                     | -50  | -    | mA   |
| T <sub>stg</sub> | storage temperature     |                                                                         | -65  | +150 | °C   |
| P <sub>tot</sub> | total power dissipation | [2]                                                                     | -    | 250  | mW   |

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SOT505-2 (TSSOP8) package: P<sub>tot</sub> derates linearly with 4.6 mW/K above 96 °C.  
For SOT765-1 (VSSOP8) package: P<sub>tot</sub> derates linearly with 4.9 mW/K above 99 °C.

10. Recommended operating conditions

Table 6. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

| Symbol           | Parameter           | Conditions | 74HC3G14-Q100 |     |                 | 74HCT3G14-Q100 |     |                 | Unit |
|------------------|---------------------|------------|---------------|-----|-----------------|----------------|-----|-----------------|------|
|                  |                     |            | Min           | Typ | Max             | Min            | Typ | Max             |      |
| V <sub>CC</sub>  | supply voltage      |            | 2.0           | 5.0 | 6.0             | 4.5            | 5.0 | 5.5             | V    |
| V <sub>I</sub>   | input voltage       |            | 0             | -   | V <sub>CC</sub> | 0              | -   | V <sub>CC</sub> | V    |
| V <sub>O</sub>   | output voltage      |            | 0             | -   | V <sub>CC</sub> | 0              | -   | V <sub>CC</sub> | V    |
| T <sub>amb</sub> | ambient temperature |            | -40           | +25 | +125            | -40            | +25 | +125            | °C   |

## 11. Static characteristics

**Table 7. Static characteristics**

Voltages are referenced to GND (ground = 0 V). All typical values are measured at  $T_{amb} = 25\text{ °C}$ .

| Symbol           | Parameter                 | Conditions                                                                                                  | 25 °C |      |      | -40 °C to +85 °C |      | -40 °C to +125 °C |      | Unit |
|------------------|---------------------------|-------------------------------------------------------------------------------------------------------------|-------|------|------|------------------|------|-------------------|------|------|
|                  |                           |                                                                                                             | Min   | Typ  | Max  | Min              | Max  | Min               | Max  |      |
| 74HC3G14-Q100    |                           |                                                                                                             |       |      |      |                  |      |                   |      |      |
| V <sub>OH</sub>  | HIGH-level output voltage | V <sub>I</sub> = V <sub>T+</sub> or V <sub>T-</sub>                                                         |       |      |      |                  |      |                   |      |      |
|                  |                           | I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 2.0 V                                                            | 1.9   | 2.0  | -    | 1.9              | -    | 1.9               | -    | V    |
|                  |                           | I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 4.5 V                                                            | 4.4   | 4.5  | -    | 4.4              | -    | 4.4               | -    | V    |
|                  |                           | I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 6.0 V                                                            | 5.9   | 6.0  | -    | 5.9              | -    | 5.9               | -    | V    |
|                  |                           | I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 4.5 V                                                           | 4.18  | 4.32 | -    | 4.13             | -    | 3.7               | -    | V    |
|                  |                           | I <sub>O</sub> = -5.2 mA; V <sub>CC</sub> = 6.0 V                                                           | 5.68  | 5.81 | -    | 5.63             | -    | 5.2               | -    | V    |
| V <sub>OL</sub>  | LOW-level output voltage  | V <sub>I</sub> = V <sub>T+</sub> or V <sub>T-</sub>                                                         |       |      |      |                  |      |                   |      |      |
|                  |                           | I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 2.0 V                                                             | -     | 0    | 0.1  | -                | 0.1  | -                 | 0.1  | V    |
|                  |                           | I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V                                                             | -     | 0    | 0.1  | -                | 0.1  | -                 | 0.1  | V    |
|                  |                           | I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 6.0 V                                                             | -     | 0    | 0.1  | -                | 0.1  | -                 | 0.1  | V    |
|                  |                           | I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 4.5 V                                                            | -     | 0.15 | 0.26 | -                | 0.33 | -                 | 0.4  | V    |
|                  |                           | I <sub>O</sub> = 5.2 mA; V <sub>CC</sub> = 6.0 V                                                            | -     | 0.16 | 0.26 | -                | 0.33 | -                 | 0.4  | V    |
| I <sub>I</sub>   | input leakage current     | V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 6.0 V                                            | -     | -    | ±0.1 | -                | ±1.0 | -                 | ±1.0 | μA   |
| I <sub>CC</sub>  | supply current            | per input pin; V <sub>CC</sub> = 6.0 V; V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A       | -     | -    | 1.0  | -                | 10   | -                 | 20   | μA   |
| C <sub>I</sub>   | input capacitance         |                                                                                                             | -     | 2.0  | -    | -                | -    | -                 | -    | pF   |
| 74HCT3G14-Q100   |                           |                                                                                                             |       |      |      |                  |      |                   |      |      |
| V <sub>OH</sub>  | HIGH-level output voltage | V <sub>I</sub> = V <sub>T+</sub> or V <sub>T-</sub>                                                         |       |      |      |                  |      |                   |      |      |
|                  |                           | I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 4.5 V                                                            | 4.4   | 4.5  | -    | 4.4              | -    | 4.4               | -    | V    |
|                  |                           | I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 4.5 V                                                           | 4.18  | 4.32 | -    | 4.13             | -    | 3.7               | -    | V    |
| V <sub>OL</sub>  | LOW-level output voltage  | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>                                                         |       |      |      |                  |      |                   |      |      |
|                  |                           | I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V                                                             | -     | 0    | 0.1  | -                | 0.1  | -                 | 0.1  | V    |
|                  |                           | I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 4.5 V                                                            | -     | 0.15 | 0.26 | -                | 0.33 | -                 | 0.4  | V    |
| I <sub>I</sub>   | input leakage current     | V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 5.5 V                                            | -     | -    | ±0.1 | -                | ±1.0 | -                 | ±1.0 | μA   |
| I <sub>CC</sub>  | supply current            | per input pin; V <sub>CC</sub> = 5.5 V; V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A       | -     | -    | 1.0  | -                | 10   | -                 | 20   | μA   |
| ΔI <sub>CC</sub> | additional supply current | per input; V <sub>CC</sub> = 4.5 V to 5.5 V; V <sub>I</sub> = V <sub>CC</sub> - 2.1 V; I <sub>O</sub> = 0 A | -     | -    | 300  | -                | 375  | -                 | 410  | μA   |
| C <sub>I</sub>   | input capacitance         |                                                                                                             | -     | 2.0  | -    | -                | -    | -                 | -    | pF   |

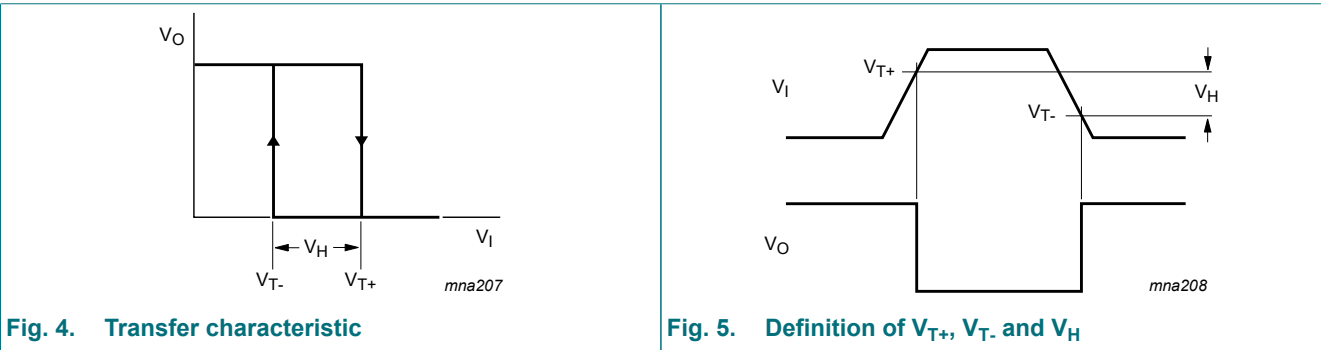
11.1. Transfer characteristics

Table 8. Transfer characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 9.

| Symbol          | Parameter                        | Conditions                                                                                                           | 25 °C |      |      | -40 °C to +85 °C |      | -40 °C to +125 °C |      | Unit |
|-----------------|----------------------------------|----------------------------------------------------------------------------------------------------------------------|-------|------|------|------------------|------|-------------------|------|------|
|                 |                                  |                                                                                                                      | Min   | Typ  | Max  | Min              | Max  | Min               | Max  |      |
| 74HC3G14-Q100   |                                  |                                                                                                                      |       |      |      |                  |      |                   |      |      |
| V <sub>T+</sub> | positive-going threshold voltage | see <a href="#">Fig. 4</a> , <a href="#">Fig. 5</a>                                                                  |       |      |      |                  |      |                   |      |      |
|                 |                                  | V <sub>CC</sub> = 2.0 V                                                                                              | 1.00  | 1.18 | 1.50 | 1.00             | 1.50 | 1.00              | 1.50 | V    |
|                 |                                  | V <sub>CC</sub> = 4.5 V                                                                                              | 2.30  | 2.60 | 3.15 | 2.30             | 3.15 | 2.30              | 3.15 | V    |
|                 |                                  | V <sub>CC</sub> = 6.0 V                                                                                              | 3.00  | 3.46 | 4.20 | 3.00             | 4.20 | 3.00              | 4.20 | V    |
| V <sub>T-</sub> | negative-going threshold voltage | see <a href="#">Fig. 4</a> , <a href="#">Fig. 5</a>                                                                  |       |      |      |                  |      |                   |      |      |
|                 |                                  | V <sub>CC</sub> = 2.0 V                                                                                              | 0.30  | 0.60 | 0.90 | 0.30             | 0.90 | 0.30              | 0.90 | V    |
|                 |                                  | V <sub>CC</sub> = 4.5 V                                                                                              | 1.13  | 1.47 | 2.00 | 1.13             | 2.00 | 1.13              | 2.00 | V    |
|                 |                                  | V <sub>CC</sub> = 6.0 V                                                                                              | 1.50  | 2.06 | 2.60 | 1.50             | 2.60 | 1.50              | 2.60 | V    |
| V <sub>H</sub>  | hysteresis voltage               | (V <sub>T+</sub> - V <sub>T-</sub> ); see <a href="#">Fig. 4</a> , <a href="#">Fig. 5</a> and <a href="#">Fig. 6</a> |       |      |      |                  |      |                   |      |      |
|                 |                                  | V <sub>CC</sub> = 2.0 V                                                                                              | 0.30  | 0.60 | 1.00 | 0.30             | 1.00 | 0.30              | 1.00 | V    |
|                 |                                  | V <sub>CC</sub> = 4.5 V                                                                                              | 0.60  | 1.13 | 1.40 | 0.60             | 1.40 | 0.60              | 1.40 | V    |
|                 |                                  | V <sub>CC</sub> = 6.0 V                                                                                              | 0.80  | 1.40 | 1.70 | 0.80             | 1.70 | 0.80              | 1.70 | V    |
| 74HCT3G14-Q100  |                                  |                                                                                                                      |       |      |      |                  |      |                   |      |      |
| V <sub>T+</sub> | positive-going threshold voltage | see <a href="#">Fig. 4</a> , <a href="#">Fig. 5</a>                                                                  |       |      |      |                  |      |                   |      |      |
|                 |                                  | V <sub>CC</sub> = 4.5 V                                                                                              | 1.20  | 1.58 | 1.90 | 1.20             | 1.90 | 1.20              | 1.90 | V    |
|                 |                                  | V <sub>CC</sub> = 5.5 V                                                                                              | 1.40  | 1.78 | 2.10 | 1.40             | 2.10 | 1.40              | 2.10 | V    |
| V <sub>T-</sub> | negative-going threshold voltage | see <a href="#">Fig. 4</a> , <a href="#">Fig. 5</a>                                                                  |       |      |      |                  |      |                   |      |      |
|                 |                                  | V <sub>CC</sub> = 4.5 V                                                                                              | 0.50  | 0.87 | 1.20 | 0.50             | 1.20 | 0.50              | 1.20 | V    |
|                 |                                  | V <sub>CC</sub> = 5.5 V                                                                                              | 0.60  | 1.11 | 1.40 | 0.60             | 1.40 | 0.60              | 1.40 | V    |
| V <sub>H</sub>  | hysteresis voltage               | (V <sub>T+</sub> - V <sub>T-</sub> ); see <a href="#">Fig. 4</a> , <a href="#">Fig. 5</a> and <a href="#">Fig. 7</a> |       |      |      |                  |      |                   |      |      |
|                 |                                  | V <sub>CC</sub> = 4.5 V                                                                                              | 0.40  | 0.71 | -    | 0.40             | -    | 0.40              | -    | V    |
|                 |                                  | V <sub>CC</sub> = 5.5 V                                                                                              | 0.40  | 0.67 | -    | 0.40             | -    | 0.40              | -    | V    |

11.2. Transfer characteristics waveforms



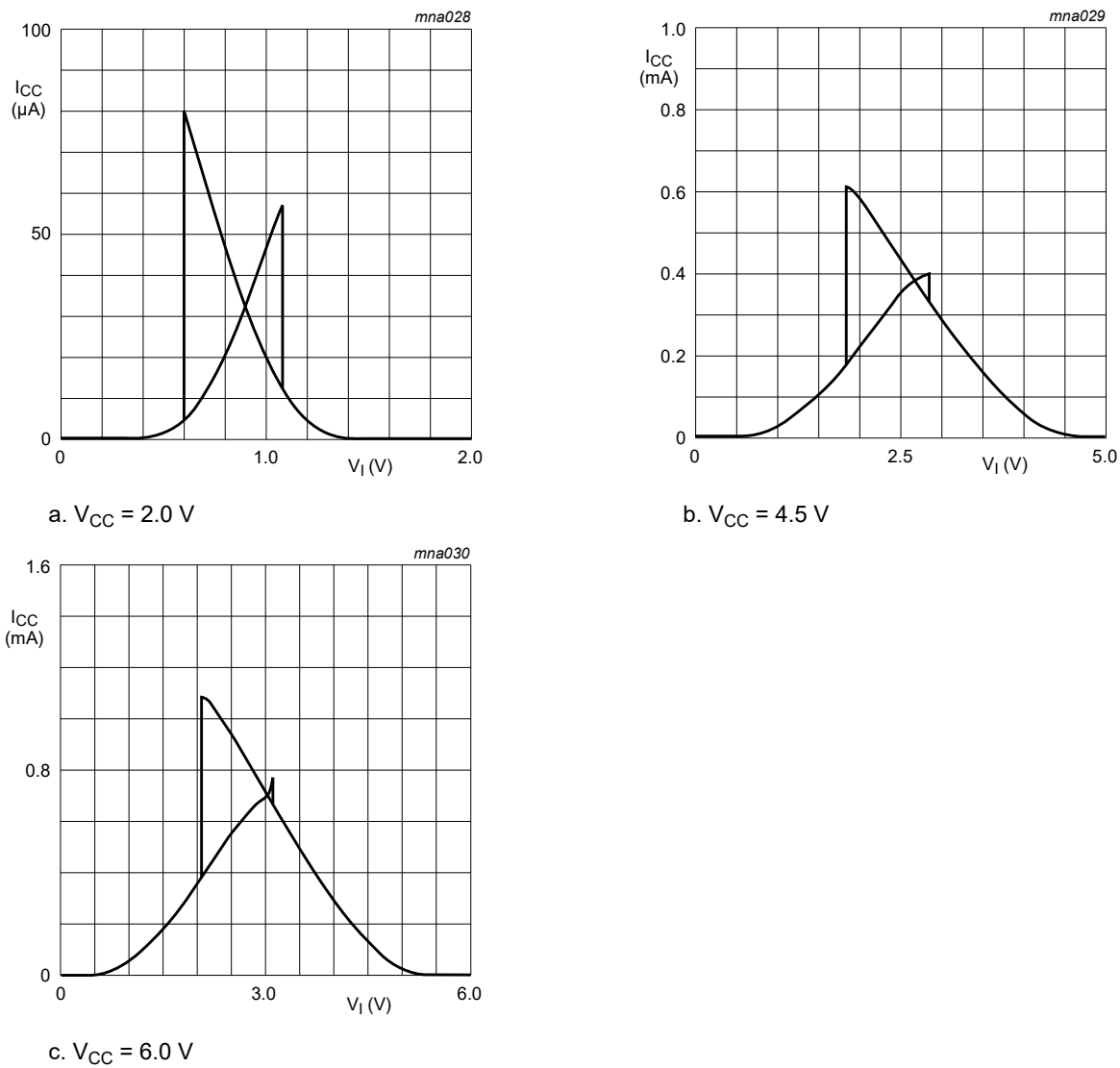


Fig. 6. Typical 74HC3G14-Q100 transfer characteristics

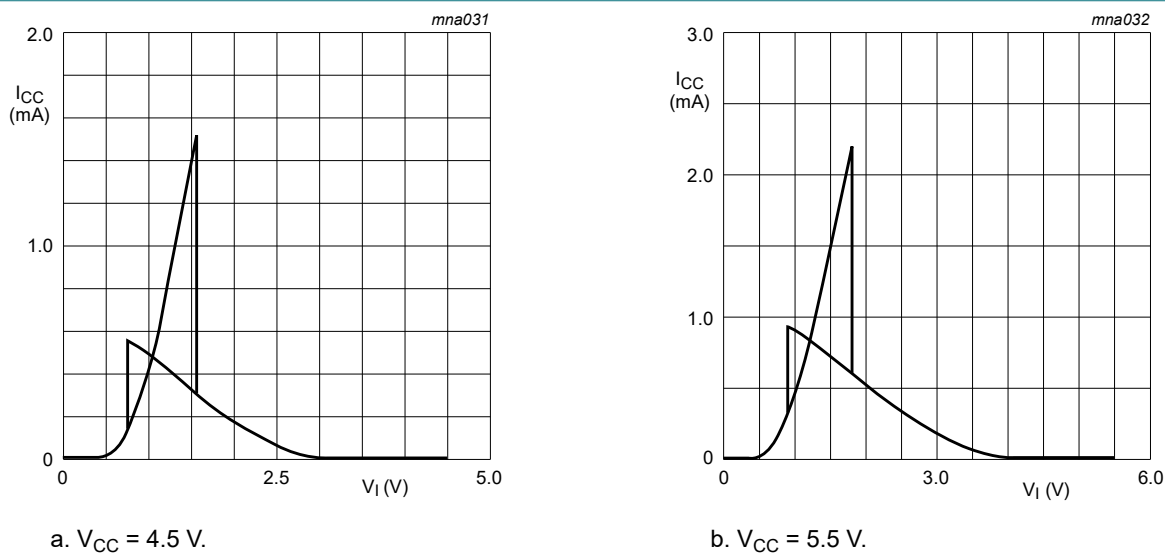


Fig. 7. Typical 74HCT3G14-Q100 transfer characteristics

## 12. Dynamic characteristics

**Table 9. Dynamic characteristics**

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 9.

| Symbol          | Parameter                     | Conditions                                                        | 25 °C |     |     | -40 °C to +85 °C |     | -40 °C to +125 °C |     | Unit |
|-----------------|-------------------------------|-------------------------------------------------------------------|-------|-----|-----|------------------|-----|-------------------|-----|------|
|                 |                               |                                                                   | Min   | Typ | Max | Min              | Max | Min               | Max |      |
| 74HC3G14-Q100   |                               |                                                                   |       |     |     |                  |     |                   |     |      |
| t <sub>pd</sub> | propagation delay             | nA to nY; see <a href="#">Fig. 8</a> [1]                          |       |     |     |                  |     |                   |     |      |
|                 |                               | V <sub>CC</sub> = 2.0 V                                           | -     | 53  | 125 | -                | 155 | -                 | 190 | ns   |
|                 |                               | V <sub>CC</sub> = 4.5 V                                           | -     | 16  | 25  | -                | 31  | -                 | 38  | ns   |
|                 |                               | V <sub>CC</sub> = 6.0 V                                           | -     | 13  | 21  | -                | 26  | -                 | 32  | ns   |
| t <sub>t</sub>  | transition time               | nY; see <a href="#">Fig. 8</a> [2]                                |       |     |     |                  |     |                   |     |      |
|                 |                               | V <sub>CC</sub> = 2.0 V                                           | -     | 20  | 75  | -                | 95  | -                 | 110 | ns   |
|                 |                               | V <sub>CC</sub> = 4.5 V                                           | -     | 7   | 15  | -                | 19  | -                 | 22  | ns   |
|                 |                               | V <sub>CC</sub> = 6.0 V                                           | -     | 5   | 13  | -                | 16  | -                 | 19  | ns   |
| C <sub>PD</sub> | power dissipation capacitance | V <sub>I</sub> = GND to V <sub>CC</sub> [3]                       | -     | 10  | -   | -                | -   | -                 | -   | pF   |
| 74HCT3G14-Q100  |                               |                                                                   |       |     |     |                  |     |                   |     |      |
| t <sub>pd</sub> | propagation delay             | nA to nY; V <sub>CC</sub> = 4.5 V; see <a href="#">Fig. 8</a> [1] | -     | 21  | 32  | -                | 40  | -                 | 48  | ns   |
| t <sub>t</sub>  | transition time               | nY; V <sub>CC</sub> = 4.5 V; see <a href="#">Fig. 8</a> [2]       | -     | 6   | 15  | -                | 19  | -                 | 22  | ns   |
| C <sub>PD</sub> | power dissipation capacitance | V <sub>I</sub> = GND to V <sub>CC</sub> - 1.5 V [3]               | -     | 10  | -   | -                | -   | -                 | -   | pF   |

[1]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$

[2]  $t_t$  is the same as  $t_{TLH}$  and  $t_{THL}$

[3]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu\text{W}$ ).

$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$  where:

$f_i$  = input frequency in MHz;

$f_o$  = output frequency in MHz;

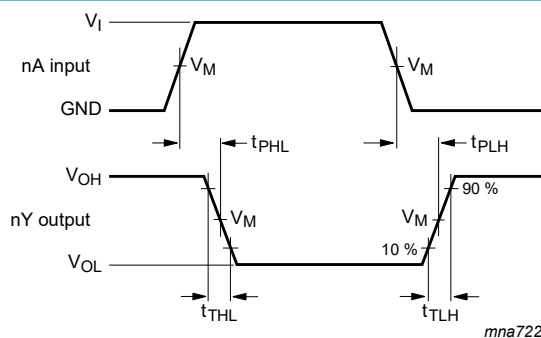
$C_L$  = output load capacitance in pF;

$V_{CC}$  = supply voltage in V;

$N$  = number of inputs switching;

$\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of the outputs.

### 12.1. Waveforms and test circuit



Measurement points are given in Table 10.

$V_{OL}$  and  $V_{OH}$  are typical voltage output levels that occur with the output load.

**Fig. 8. The data input (nA) to output (nY) propagation delays and output transition times**

Table 10. Measurement points

| Type           | Input               | Output              |
|----------------|---------------------|---------------------|
|                | $V_M$               | $V_M$               |
| 74HC3G14-Q100  | $0.5 \times V_{CC}$ | $0.5 \times V_{CC}$ |
| 74HCT3G14-Q100 | 1.3 V               | 1.3 V               |

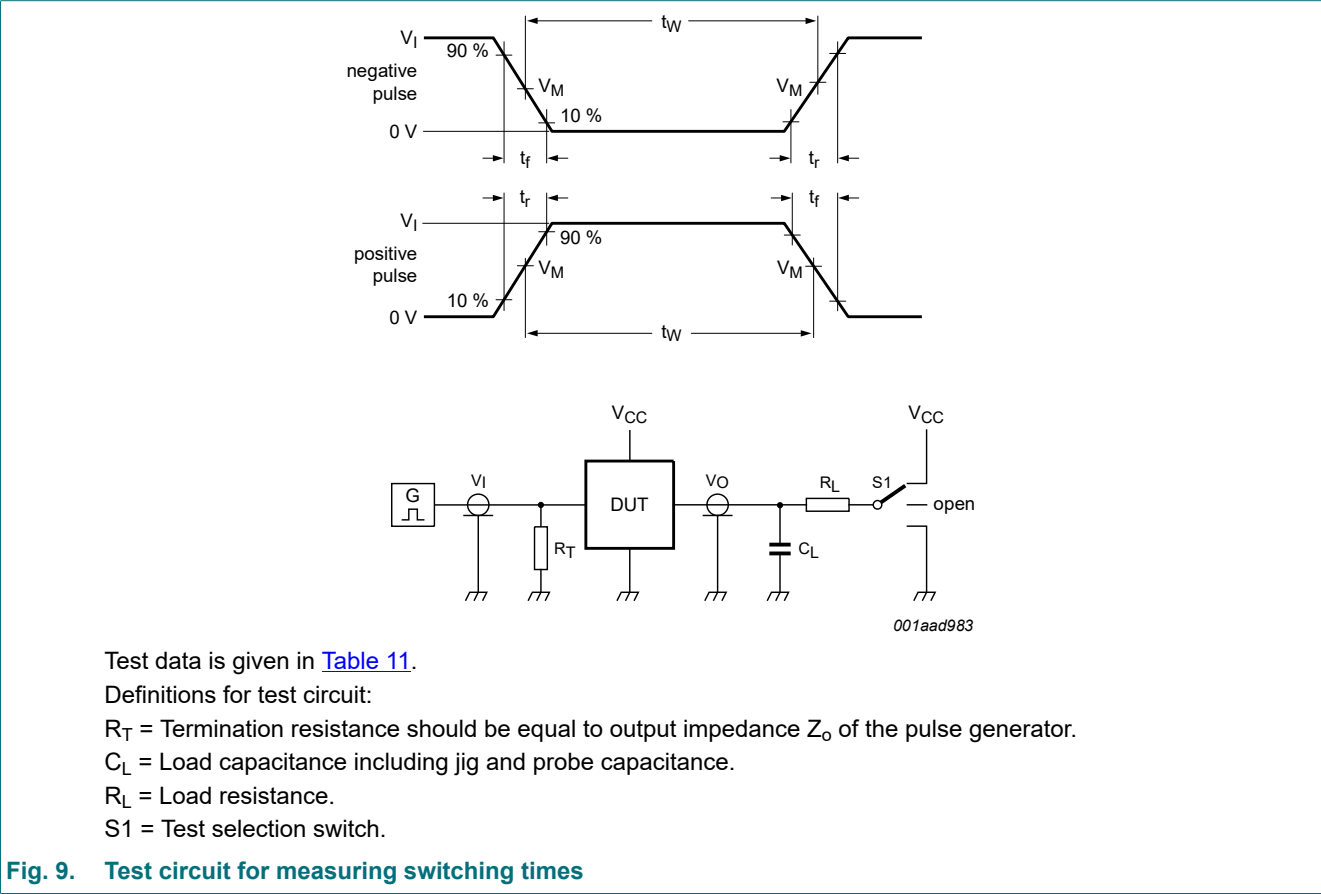


Fig. 9. Test circuit for measuring switching times

Table 11. Test data

| Type           | Input           |             | Load  |              | S1 position        |
|----------------|-----------------|-------------|-------|--------------|--------------------|
|                | $V_I$           | $t_r, t_f$  | $C_L$ | $R_L$        | $t_{PHL}, t_{PLH}$ |
| 74HC3G14-Q100  | GND to $V_{CC}$ | $\leq 6$ ns | 50 pF | 1 k $\Omega$ | open               |
| 74HCT3G14-Q100 | GND to 3.0 V    | $\leq 6$ ns | 50 pF | 1 k $\Omega$ | open               |

### 13. Application information

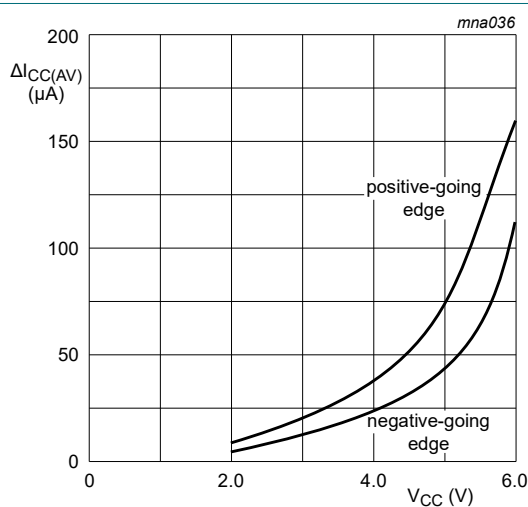
The slow input rise and fall times cause additional power dissipation, which can be calculated using the following formula:

$$P_{\text{add}} = f_i \times (t_r \times \Delta I_{\text{CC(AV)}} + t_f \times \Delta I_{\text{CC(AV)}}) \times V_{\text{CC}} \text{ where:}$$

- $P_{\text{add}}$  = additional power dissipation ( $\mu\text{W}$ );
- $f_i$  = input frequency (MHz);
- $t_r$  = input rise time (ns); 10 % to 90 %;
- $t_f$  = input fall time (ns); 90 % to 10 %;
- $\Delta I_{\text{CC(AV)}}$  = average additional supply current ( $\mu\text{A}$ ).

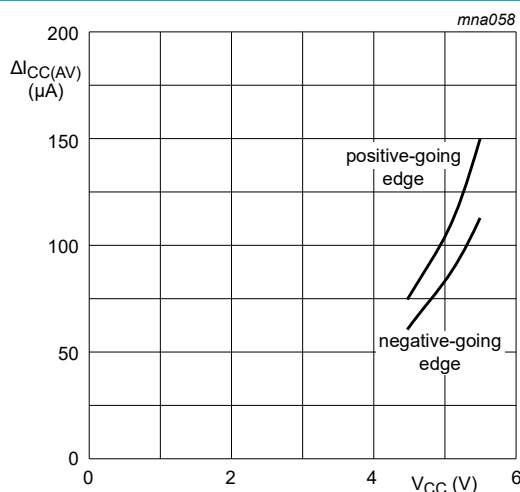
$\Delta I_{\text{CC(AV)}}$  differs with positive or negative input transitions, as shown in [Fig. 10](#) and [Fig. 11](#).

An example of a relaxation circuit using the 74HC3G14-Q100/74HCT3G14-Q100 is shown in [Fig. 12](#).



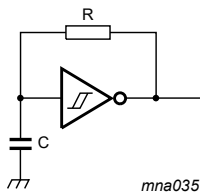
Linear change of  $V_I$  between  $0.1 \times V_{\text{CC}}$  to  $0.9 \times V_{\text{CC}}$ .

**Fig. 10.  $\Delta I_{\text{CC(AV)}}$  as a function of  $V_{\text{CC}}$  for 74HC3G14-Q100**



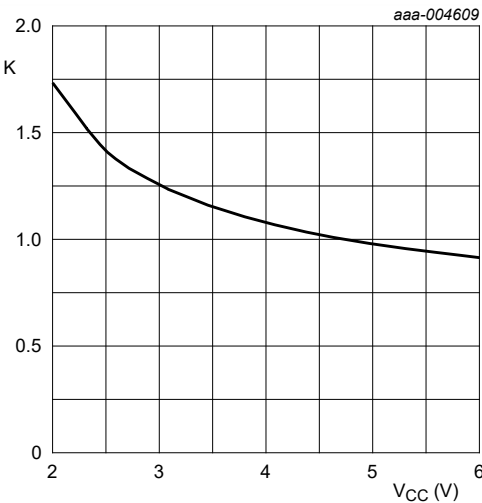
Linear change of  $V_I$  between  $0.1 \times V_{\text{CC}}$  to  $0.9 \times V_{\text{CC}}$ .

**Fig. 11.  $\Delta I_{\text{CC(AV)}}$  as a function of  $V_{\text{CC}}$  for 74HCT3G14-Q100**

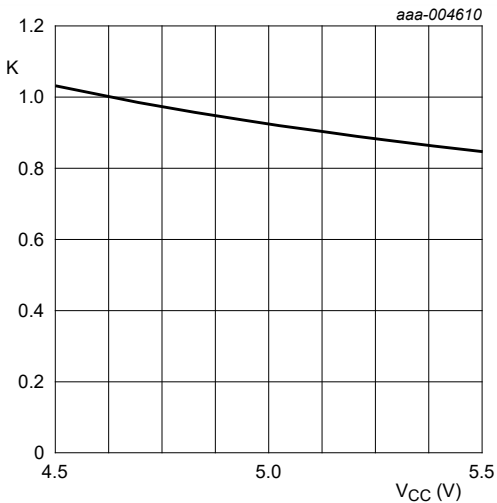


For 74HC3G14-Q100:  $f = \frac{1}{T} \approx \frac{1}{0.8 \times RC}$   
For 74HCT3G14-Q100:  $f = \frac{1}{T} \approx \frac{1}{0.67 \times RC}$   
For K-factor, see [Fig. 13](#)

Fig. 12. Relaxation oscillator



a. K-factor for 74HC3G14-Q100



b. K-factor for 74HCT3G14-Q100

Fig. 13. Typical K-factor for relaxation oscillator

14. Package outline

TSSOP8: plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm    SOT505-2

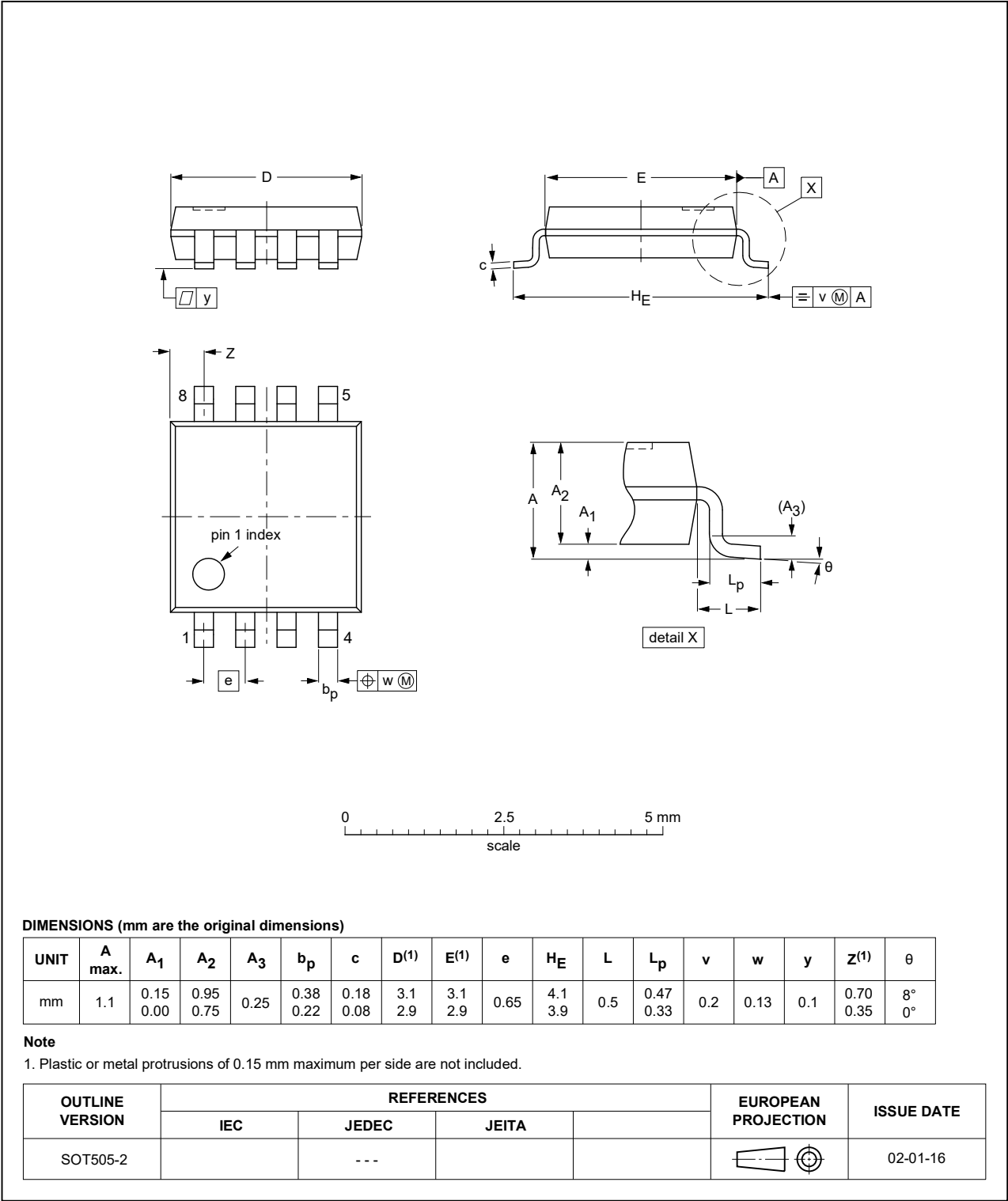


Fig. 14. Package outline SOT505-2 (TSSOP8)

VSSOP8: plastic very thin shrink small outline package; 8 leads; body width 2.3 mm

SOT765-1

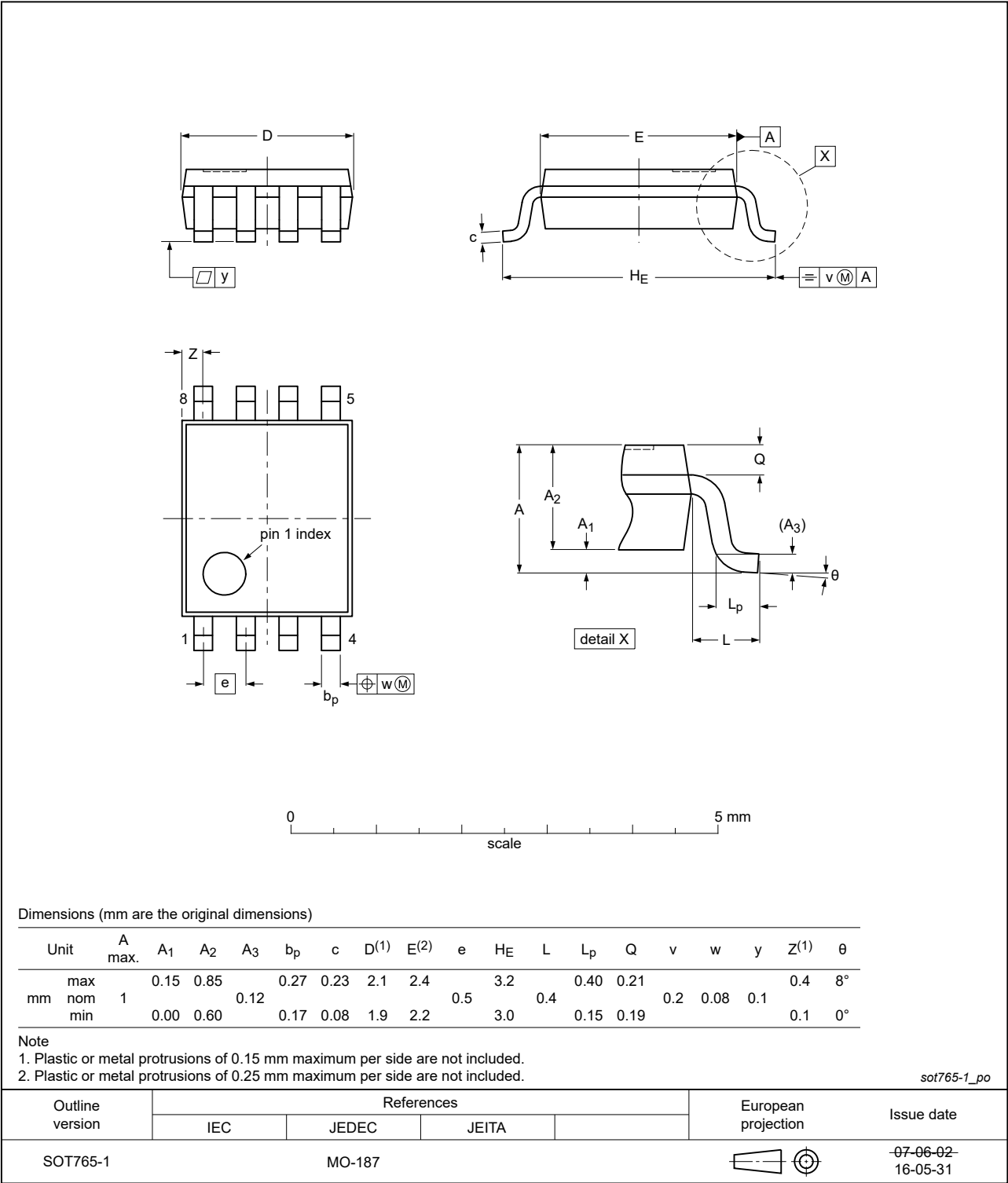


Fig. 15. Package outline SOT765-1 (VSSOP8)

## 15. Abbreviations

Table 12. Abbreviations

| Acronym | Description                             |
|---------|-----------------------------------------|
| CDM     | Charged Device Model                    |
| CMOS    | Complementary Metal-Oxide Semiconductor |
| DUT     | Device Under Test                       |
| ESD     | ElectroStatic Discharge                 |
| HBM     | Human Body Model                        |
| TTL     | Transistor-Transistor Logic             |

## 16. Revision history

Table 13. Revision history

| Document ID           | Release date                                                                                                                                                                                                                                                                                                                            | Data sheet status  | Change notice | Supersedes            |
|-----------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------|---------------|-----------------------|
| 74HC_HCT3G14_Q100 v.4 | 20231218                                                                                                                                                                                                                                                                                                                                | Product data sheet | -             | 74HC_HCT3G14_Q100 v.3 |
| Modifications:        | <ul style="list-style-type: none"> <li>• <a href="#">Section 2</a> updated.</li> <li>• <a href="#">Section 2</a>: ESD specification updated according to the latest JEDEC standard.</li> <li>• <a href="#">Section 9</a>: <math>P_{tot}</math> and derating values for <math>P_{tot}</math> total power dissipation updated.</li> </ul> |                    |               |                       |
| 74HC_HCT3G14_Q100 v.3 | 20190201                                                                                                                                                                                                                                                                                                                                | Product data sheet | -             | 74HC_HCT3G14_Q100 v.2 |
| Modifications:        | <ul style="list-style-type: none"> <li>• The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>• Legal texts have been adapted to the new company name where appropriate.</li> <li>• Package outline drawing <a href="#">SOT765-1</a> (VSSOP8) updated.</li> </ul>             |                    |               |                       |
| 74HC_HCT3G14_Q100 v.2 | 20131209                                                                                                                                                                                                                                                                                                                                | Product data sheet | -             | 74HC_HCT3G14_Q100 v.1 |
| Modifications:        | <ul style="list-style-type: none"> <li>• <a href="#">Fig. 13</a> added (typical K-factor for relaxation oscillator).</li> </ul>                                                                                                                                                                                                         |                    |               |                       |
| 74HC_HCT3G14_Q100 v.1 | 20131115                                                                                                                                                                                                                                                                                                                                | Product data sheet | -             | -                     |

## 17. Legal information

### Data sheet status

| Document status [1][2]         | Product status [3] | Definition                                                                            |
|--------------------------------|--------------------|---------------------------------------------------------------------------------------|
| Objective [short] data sheet   | Development        | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification      | This document contains data from the preliminary specification.                       |
| Product [short] data sheet     | Production         | This document contains the product specification.                                     |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <https://www.nexperia.com>.

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